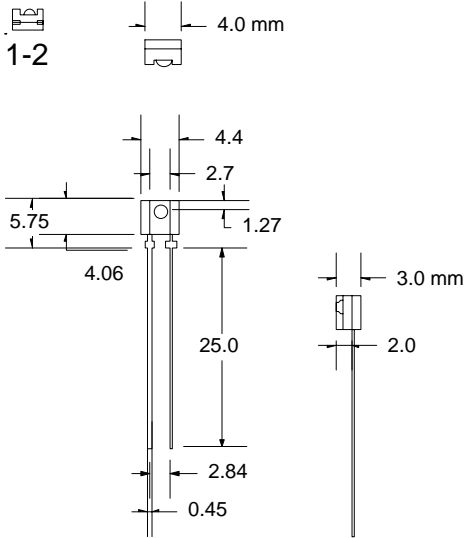
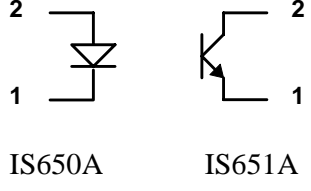


IS650A IS651A MATCHED EMITTER DETECTOR PAIR PHOTO TRANSISTOR OUTPUT

ISOCOM[®] LTD

PACKAGES	CIRCUIT
	 <p>IS650A IS651A</p>

DESCRIPTION

The IS650A (Gallium Arsenide Infrared Emitting Diode) and the IS651A (NPN Silicon Photo Transistor) are matched Emitter Detector Pair mounted in clear plastic lateral side looking packages which enables these devices to display superior mechanical resolution, coupled characteristics and reliability in a low cost housing.

Isocom Ltd supplies a multitude of plastic optocouplers for all applications varying from standard transistor optos through to Darlington and Schmitt Trigger devices. It's massive family of optos vary in speed allowing maximum opportunity to engineers worldwide.

All devices are performance guaranteed between -20°C and +80°C and have completed rigorous testing. The Company's customers can be assured of our commitment to stringent quality, reliability and inspection standards, as demonstrated by our existing approvals. Other customer specific options can also be offered.

FEATURES

- Lateral Side Looking Clear Plastic
- High Current transfer ratio

Isocom Ltd reserves the right to change the details on this specification without notice. Please consult Isocom Ltd prior to use. Isocom Ltd cannot accept liability for any errors or omissions.

For sales enquiries, or further information, please contact our sales office at:

Isocom Ltd, Hutton Close, Crowther Industrial Estate, District 3, Washington, NE38 0AH

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Or go to the Isocom Website @: [Http://www.isocom.uk.com](http://www.isocom.uk.com)

ABSOLUTE MAXIMUM RATINGS

Storage Temperature	-55°C to +150°C
Operating Temperature	-55°C to +100°C
Lead Soldering Temperature	260°C 1.6mm from case for 10S

Infrared Emitting Diode

Forward DC Current	50mA	
Reverse DC Voltage	5V	
Peak forward Current	3.0A	1μS p.w. 300 pps
Power Dissipation	100mW	Derate linearly above 25°C at 1.33mW/°C.

Output Photo Darlington Transistor

Collector-Emitter Voltage	30V	BV _{CEO}
Emitter-collector voltage	5V	BV _{ECO}
Power Dissipation	75mW	

ELECTRICAL CHARACTERISTICS

T_A = 25°C U.O.S. (each channel where appropriate).

Input Diode Electrical Characteristics

Parameter	Symbol	Test Conditions	Device	Min	Typ	Max	Units
Forward Voltage	V _F	I _F = 10mA		1.0		1.3	V
Reverse Current	I _R	V _R = 5.0V				10	μA
Reverse Breakdown Voltage	V _R	I _R = 10μA		5.0			V

Output Detector Electrical Characteristics

Collector-emitter Voltage	BV _{CEO}	I _C = 1mA		30			V
Emitter-collector Voltage	BV _{ECO}	I _E = 100μA		5			V
Collector-emitter Dark Current	I _{CEO}	V _{CE} = 10V, E _c = 0*				100	nA

Coupled Electrical Characteristics

Collector-Emitter Saturation Voltage	V _{CE(Sat)}	I _F = 20mA, I _C = 1.0mA				0.4	V
On-State Collector Current (Distance from Tip of Lens to Tip of Lens is 0.125" (3.18mm))	I _{C(ON)}	I _F = 20mA, V _{CE} = 10V		1.0			mA
Output Rise Time	T _R	V _{CC} = 5V, I _C = 1mA, R _L = 100Ω			6.0		μS
Output Fall Time	T _F				6.0		μS

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